

Monolithic Dual Switching Diode Common Cathode

- Pb-Free Package is Available.

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Rating	Symbol	Max	Unit
Reverse Voltage	V_R	70	Vdc
Forward Current	I_F	200	mAdc
Peak Forward Surge Current	$I_{FM(surge)}$	500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board ⁽¹⁾ $T_A = 25^\circ\text{C}$	P_D	225	mW
Derate above 25°C		1.8	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C/W}$
Total Device Dissipation Alumina Substrate ⁽²⁾ $T_A = 25^\circ\text{C}$	P_D	300	mW
Derate above 25°C		2.4	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

DEVICEMARKING

LBAV70LT1 = A4

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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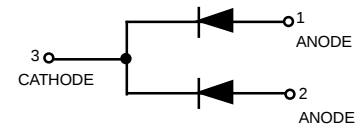
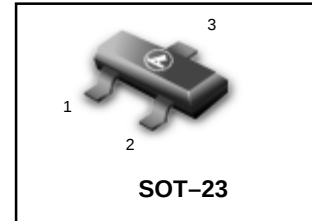
OFF CHARACTERISTICS

Reverse Breakdown Voltage ($I_{(BR)} = 100 \mu\text{Adc}$)	$V_{(BR)}$	70	—	Vdc
Reverse Voltage Leakage Current ($V_R = 25 \text{ Vdc}, T_J = 150^\circ\text{C}$)	I_R	—	60	μAdc
($V_R = 70 \text{ Vdc}$)		—	2.5	
($V_R = 70 \text{ Vdc}, T_J = 150^\circ\text{C}$)		—	100	
Diode Capacitance ($V_R = 0, f = 1.0 \text{ MHz}$)	C_D	—	1.5	pF
Forward Voltage ($I_F = 1.0 \text{ mAdc}$)	V_F	—	715	mVdc
($I_F = 10 \text{ mAdc}$)		—	855	
($I_F = 50 \text{ mAdc}$)		—	1000	
($I_F = 150 \text{ mAdc}$)		—	1250	
Reverse Recovery Time $R_L = 100\Omega$ ($I_F = I_R = 10 \text{ mAdc}, V_R = 5.0 \text{ Vdc}, I_{R(REC)} = 1.0 \text{ mAdc}$) (Figure 1)	t_{rr}	—	6.0	ns

1. FR-5 = $1.0 \times 0.75 \times 0.062 \text{ in.}$

2. Alumina = $0.4 \times 0.3 \times 0.024 \text{ in.}$ 99.5% alumina.

LBAV70LT1



ORDERING INFORMATION

Device	Marking	Shipping
LBAV70LT1	A4	3000 Tape & Reel
LBAV70LT1G	A4(Pb-Free)	3000 Tape & Reel

LBAV70LT1

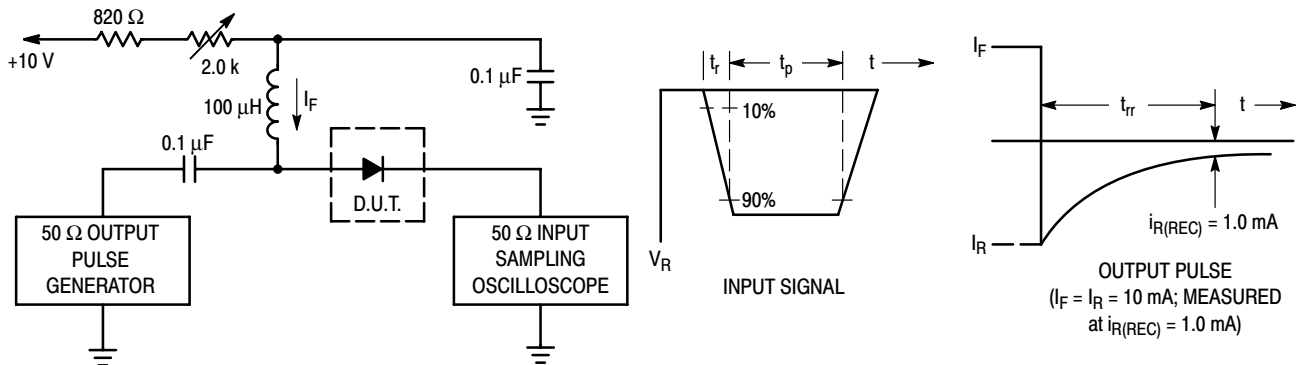
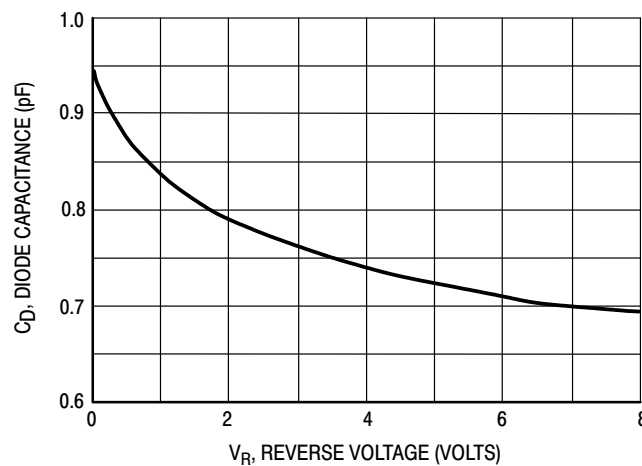
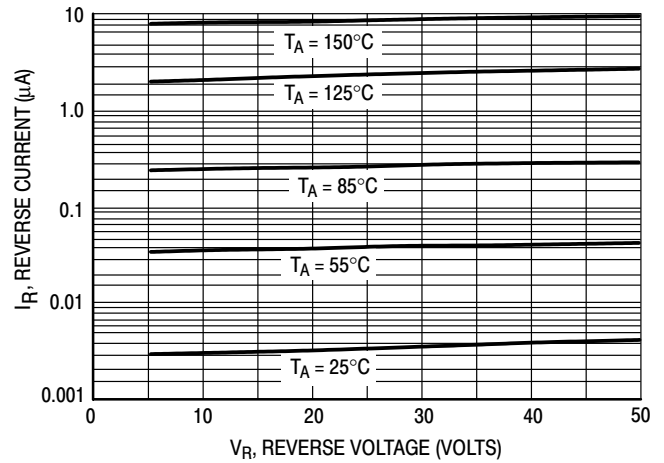
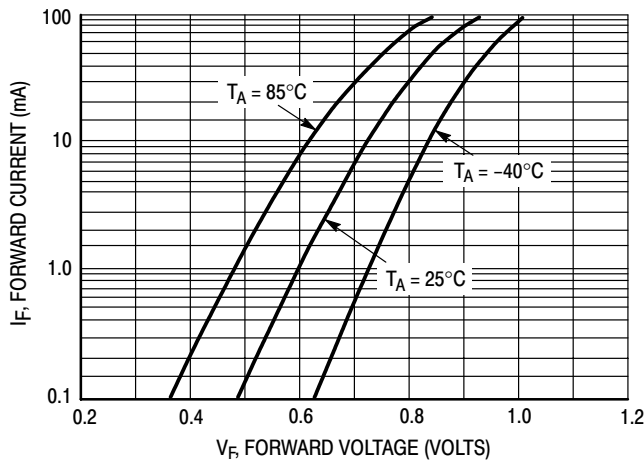
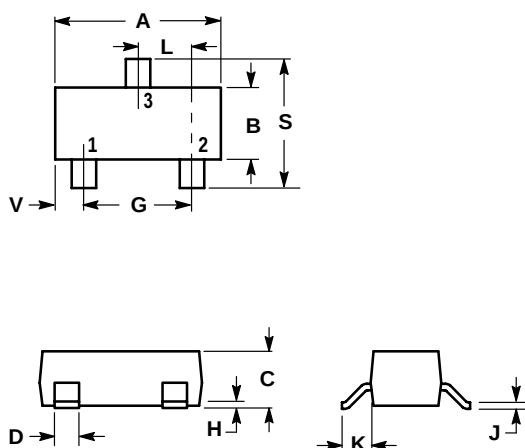


Figure 1. Recovery Time Equivalent Test Circuit

Curves Applicable to Each Anode



LBAV70LT1
SOT-23

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

PIN 1. ANODE
2. ANODE
3. CATHODE

